NSN 5961-01-451-6176

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-451-6176 **Inclosure Material:** Metal **Overall Length:** Between 0.293 inches and 0.357 inches **Terminal Length:** Between 1.000 inches and 1.625 inches **Overall Width:** Between 0.215 inches and 0.235 inches **Mounting Method: Terminal Terminal Circle Diameter:**

Between 0.025 inches and 0.035 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, dc

Current Rating Per Characteristic:

1.00 milliamperes forward current, average peak

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector absolute

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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